


APPLICATION DATA SHEET

Electronic Version v14

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Title of Invention	PROCESS FOR PLANARIZING ARRAY TOP OXIDE IN VERTICAL MOSFET DRAM ARRAYS		
Application Type : regular, utility Attorney Docket Number : NTCP0008USA			
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as our attorney(s) or agent(s) to prosecute the application identified above, and to transact all business in the United States Patent and Trademark Office connected therewith.